

Supply \* Sub Assemblies \* Taping/ Forming Components Co. Reg. No: 45730100K

### **CHIP CAPACITORS**

#### 1. DESCRIPTION

MLCC consists of a conducting material and electrodes. To manufacture a chip-type SMT and achieve miniaturization, high density and high efficiency, ceramic condensers are used.

WTC's MLCC is made by NPO, X7R and Y5V dielectric material and which provides product with high electrical precision, stability and reliability.

#### 2. FEATURES

- a. A wide selection of sizes is available (0402 to 1812).
- b. High capacitance in given case size.
- c. Capacitor with lead-free termination (pure Tin).

#### 3. APPLICATIONS

- a. For general digital circuit.
- b. For power supply bypass capacitors.
- c. For consumer electronics.
- d. For telecommunication.

#### 4. HOW TO ORDER

1206	E	<u>104</u>	<u>Z</u>	<u>500</u>	<u>c</u>	I
Size	Dielectric	Capacitance	Tolerance	Rated voltage	Termination	Packaging style
Inch (mm)	N=NP0	Two significant	B=±0.1pF	Two significant digits	L=Ag/Ni/Sn	T=7" reeled
0402 (1005)	(COG)	digits followed by	C=±0.25pF	followed by no. of zeros.	(for NPO dielectric)	R=7" reeled (2mm
0603 (1608)		no. of zeros. And R	D=±0.5pF	And R is in place of	C=Cu/Ni/Sn	pitch for 0603 size;
0805 (2012)	Same recognitions	is in place of	F=±1%	decimal point.	(for X7R, Y5V dielectric)	paper tape)
1206 (3216)		decimal point.	G=±2%			G=13" reeled
1210 (3225)			J=±5%	100=10 VDC		
1812 (4532)		eg.:	K=±10%	160=16 VDC		
,		R47=4.7pF	M=±20%	250=25 VDC		
		0R5=0.5pF	Z=-20/+80%	500=50 VDC		
		1R0=1.0pF		101=100 VDC		
		104=10x10 <sup>4</sup>				
		=100nF	_			

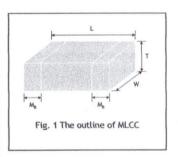


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### 5. EXTERNAL DIMENSIONS

Size Inch (mm)	L (mm)	W (mm)	T (mm)/Symbo	ol	Remark	M <sub>B</sub> (mm)
0402 (1005)	1.00±0.05	0.50±0.05	0.50±0.05	N	#	0.25 +0.05/-0.10
	1.60±0.10	0.80±0.10	0.80±0.07	5		
0603 (1608)	1.60 +0.15/-0.10	0.80 +0.15/-0.10	0.80 +0.15/-0.10	Х		0.40±0.15
			0.60±0.10	Α		
0805 (2012)	2.00±0.15	1.25±0.10	0.80±0.10	В		0.50±0.20
			1.25±0.10	D	#	
			0.80±0.10	В		
	3.20±0.15	1.60±0.15	0.95±0.10	C		
1204 (2214)	3.20±0.15	1.60±0.15	1.15±0.15	J	#	0.60±0.20
1206 (3216)			1.25±0.10	D	#	0.60±0.20
	3.20±0.20	1.60±0.20	1.60±0.20	G	#	
	3.20+0.3/-0.1	1.60+0.3/-0.1	1.60+0.30/-0.10	Р	#	
	3.20±0.30	2.50+0.20	0.95±0.10	C	#	
1210 (3225)	3.20±0.30	2.50±0.20	1.25±0.10	D	#	0.75±0.25
1210 (3223)	3.20±0.40	2,50±0,30	1.60±0.20	G	#	0.73±0.23
	3.20±0.40	2.30±0.30	2.50±0.30	М	#	
1812 (4532)	4.50±0.40	3.20±0.30	1.25±0.10	D	#	0.75±0.25
1012 (4332)	4.3010.40	3.2010.30	2.00±0.20	K	#	0.7310.23



#### 6. GENERAL ELECTRICAL DATA

Dielectric	NP0	X7R	Y5V
Size	0402, 0603,	0805, 1206, 1210, 1812	
Capacitance range*	0.5pF to 0.039uF	100pF to1.0uF	10nF to 680nF
Capacitance tolerance**	Cap≤5pF: B (±0.1pF), C (±0.25pF) 5pF <cap<10pf: (±0.25pf),="" (±0.5pf)<br="" c="" d="">Cap≥10pF: F (±1%), G (±2%), J (±5%), K (±10%)</cap<10pf:>	J (±5%), K (±10%), M (±20%)	M (±20%), Z (-20/+80%)
Rated voltage (WVDC)	16V, 25V, 50V, 100V	10V, 16V, 25V	V, 50V, 100V
Tan δ*	Cap<30pF: Q≥400+20C Cap≥30pF: Q≥1000	Note	e 1
Insulation resistance at Ur	≥10GΩ or RxC	≥500ΩxF whichever is less	
Operating temperature	-55 to +125°C		-25 to +85°C
Capacitance characteristic	±30ppm	±15%	+30/-80%
Termination	Ni/Sn (le	ead-free termination)	

<sup>\*</sup> Measured at the condition of 30-70% related humidity.

NPO: Apply 1.0 $\pm$ 0.2Vrms, 1.0MHz $\pm$ 10% for Cap $\pm$ 1000pF and 1.0 $\pm$ 0.2Vrms, 1.0kHz $\pm$ 10% for Cap $\pm$ 1000pF, 25 $^{\circ}$ C at ambient temperature X7R: Apply 1.0 $\pm$ 0.2Vrms, 1.0kHz $\pm$ 10%, at 25 $^{\circ}$ C ambient temperature.

Note 1: X7R/X5R

Rated vol.	D.F.	Excep	tion of D.F.
≥50V	≤2.5%	≤3%	0603≥0.047μF; 0805≥0.18μF, 1206≥0.47μF
	1	≤5%	0805≥1μF;
25V	≤3.5%	≤7%	0603≥0.33μF
		10%	0402≥0.10μF;0603≥0.68μF
16V	≤3.5%	≤5%	0402≥0.033μF; 0603≥0.15μF; 0805≥0.68μF;
		≤10%	0603≥0.68μF
10V	≤5.0%	≤10%	0603≥0.33μF;

Y5V

Rated vol.	D.F.	Excep	tion of D.F.
≥50V	≤5.0%	7.0%	0603≥0.1μF; 0805≥0.47μF
25V	≤5.0%	≤7%	0402≥0.047μF; 0603≥0.1μF; 0805≥0.33μF; 1206≥1μF
		≤9%	0402≥0.068μF; 0603≥0.47μF
16V (C<1.0μF)	≤7.0%	≤9%	0402≥0.068µF; 0603≥0.68µF
16V (C≥1.0µF)	≤9.0%		-
10V	≤12.5%		0402≥0.47μF

<sup>#</sup> Reflow soldering only is recommended.

Y5V: Apply 1.0±0.2Vrms, 1.0kHz±10%, at 20°C ambient temperature.

<sup>\*\*</sup> Preconditioning for Class II MLCC: Perform a heat treatment at  $150\pm10^{\circ}$ C for 1 hour, then leave in ambient condition for  $24\pm2$  hours before measurement.



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### **CHIP CAPACITORS**

#### 7. CAPACITANCE RANGE (NPO Dielectric - Noble Metal Electrode)

7-1 0402, 0603, 0805 Sizes

	DIELECTRIC								NP0							
	SIZE			0402					0603					0805		
RATE	D VOLTAGE (VDC)	10	16	25	50	100	10	16	25	50	100	10	16	25	50	100
	0.5pF (0R5)	N	N	N	N	N	S	S	S	S	S	A	Α	Α	Α	Α
	0.6pF (0R6)	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	0.7pF (0R7)	N	N	N	N	N	S	S	S	S	S	Α	Α	A	Α	Α
	0.8pF (0R8)	N	N	N	N	N	S	S	S	S	S	Α	Α	A	Α	Α
	0.9pF (0R9)	N	N	N	N	N	S	S	S	S	S	A	Α	Α	Α	A
	1.0pF (1R0)	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	A
	1.2pF (1R2)	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	A
	1.5pF (1R5)	N	N	N	N	N	S	S	S	S	S	Α	Α	A	Α	Α
	1.8pF (1R8)	N	N	N	N	N	5	S	S	S	S	A	Α	A	Α	Α
	2.2pF (2R2)	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	2.7pF (2R7)	N	N	N	N	N	S	S	S	S	S	A	Α	A	Α	Α
	3.3pF (3R3)	N	N	N	N	N	S	S	S	S	S	A	Α	A	Α	Α
	3.9pF (3R9)	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	A
	4.7pF (4R7)	N	N	N	N	N	S	S	5	S	S	A	Α	A	Α	A
	5.6pF (5R6)	N	N	N	N	N	S	5	S	S	5	A	Α	A	A	A
	6.8pF (6R8)	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	A
	8.2pF (8R2)	N	N	N	N	N	S	S	S	S	S	A	Α	A	A	A
	10pF (100)	N	N	N	N	N	S	S	S	S	5	A	Α	A	A	A
	12pF (120)	N	N	N	N	N	S	S	S	S	S	Α	Α	A	Α	Α
o	15pF (150)	N	N	N	N	N	S	S	S	S	S	A	Α	A	Α	A
Capacitance	18pF (180)	N	N	N	N	N	S	S	S	5	5	A	Α	A	Α	A
ac	22pF (220)	N	N	N	N	N	S	S	S	S	S	A	Α	A	Α	Α
Cap	27pF (270)	N	N	N	N	N	S	S	S	S	S	A	Α	A	Α	A
	33pF (330)	N	N	N	N	N	S	5	S	S	S	A	A	A	Α	Α
	39pF (390)	N	N	N	N	N	S	5	S	S	5	A	Α	Α	A	Α
	47pF (470)	N	N	N	N	N	S	5	S	S	S	A	Α	Α	Α	Α
	56pF (560)	N	N	N	N	N	5	5	S	S	S	A	A	A	Α	Α
	68pF (680)	N	N	N	N	N	S	S	S	S	5	A	Α	A	A	A
	82pF (820)	N	N	N	N	N	S	S	S	S	S	A	Α	A	Α	A
	100pF (101)	N	N	N	N	N	S	S	S	S	S	A	A	A	A	A
	120pF (121)	N	N	N	N	N	S	S	S	S	S	A	Α	A	A	A
	150pF (151)	N	N	N	N	N	S	S	S	S	S	A	Α	A	Α	A
	180pF (181)	N	N	N	N		S	S	S	S	S	A	Α	A	A	A
	220pF (221)	N	N	N	N		S	S	S	S	S	A	Α	A	A	A
	270pF (271)	N	N	N	1	1	S	S	S	S	S	A	A	A	A	A
	330pF (331)	N	N		1		S	S	S	S	5	A	Α	A	A	A
	390pF (391)	N	N	1	T		S	S	S	S	S	В	В	В	В	В
	470pF (471)	N	N			1	S	S	5	S	5	В	В	В	В	В
	560pF (561)				1		S	S	S	S	5	В	В	В	В	В
	680pF (681)				1		S	5	5	S	S	В	В	В	В	В
	820pF (821)	-	-		1	-	S	S	S	S	-	В	В	В	В	В
	1,000pF (102)		-	-	1	1	S	S	S	S	1	В	В	В	В	В

<sup>1.</sup> The letter in cell is expressed the symbol of product thickness.



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### **CHIP CAPACITORS**

7-1 0402, 0603, 0805 Sizes (Continued)

	DIELECTRIC		No. of					NP	0						ALTERNATION OF THE PARTY OF THE
	SIZE		0402					0603					0805		
RATE	D VOLTAGE (VDC)	10 16	25	50	100	10	16	25	50	100	10	16	25	50	100
Account.	1,200pF (122)					S	S				В	В	В	В	В
	1,500pF (152)					S	S				В	В	В	В	В
	1,800pF (182)					S	S				В	В	В	В	В
	2,200pF (222)					S	S				В	В	В	В	В
· O	2,700pF (272)					S	S				D	D	D	D	D
DO.	3,300pF (332)					S	S				D	D	D	D	D
Capacitance	3,900pF (392)										D	D	D	D	D
pa	4,700pF (472)										D	D	D	D	
Ü	5,600pF (562)										D	D		<u> </u>	
	6,800pF (682)										D	D			
	8,200pF (822)		-								D	D			
	0.010µF (103)										D	D			
	0.012µF (123)	THE REAL PROPERTY AND ADDRESS OF THE PERSON NAMED IN COLUMN TWO PERSONS ASSESSMENT OF THE PERSON NAMED IN COLUMN TWO PERSONS ASSESSMENT OF THE PERSON NAMED IN COLUMN TWO PERSONS ASSESSMENT OF THE PERSON NAMED IN COLUMN TWO PERSON NAMED IN COLUMN TRANSPORT OF THE PERSON NAMED IN COLUMN TWO PERSON NAMED IN COLUMN TRANSPORT NAMED IN COLUMN TWO PERSON NAMED IN COLUMN TRANSPORT NAMED IN COLUMN TWO PERSON NAMED IN COLUMN TRANSPORT NAMED IN COLUMN TWO PERSON NAMED IN COLUMN TWO PERS									D	D			

<sup>1.</sup> The letter in cell is expressed the symbol of product thickness.

#### 7-2 1206, 1210, 1812 Sizes

	DIELECTRIC							San San	NPO					
	SIZE			1206	Nation 1				1210				1812	
RATI	ED VOLTAGE (VDC)	10	16	25	50	100	10	16	25	50	100	16	50	100
	1.0pF (1R0)													
	1.2pF (1R2)											-		
	1.5pF (1R5)	В	В	В	В	В								
	1.8pF (1R8)	В	В	В	В	В								
	2.2pF (2R2)	В	В	В	В	В								
	2.7pF (2R7)	В	В	В	В	В								
	3.3pF (3R3)	В	В	В	В	В								
	3.9pF (3R9)	В	В	В	В	В								
	4.7pF (4R7)	В	В	В	В	В								
	5.6pF (5R6)	В	В	В	В	В								
0	6.8pF (6R8)	В	В	В	В	В								
Capacitance	8.2pF (8R2)	В	В	В	В	В								
t t	10pF (100)	В	В	В	В	В					C			D
apa	12pF (120)	В	В	В	В	В					C			D
Ü	15pF (150)	В	В	В	В	В					C			D
	18pF (180)	В	В	В	В	В					С			D
	22pF (220)	В	В	В	В	В	C	C	C	C	C			D
	27pF (270)	В	В	В	В	В	C	C	C	C	C			D
	33pF (330)	В	В	В	В	В	С	С	C	C	C			D
	39pF (390)	В	В	В	В	В	C	С	C	С	C			D
	47pF (470)	В	В	В	В	В	C	С	C	C	C			D
	56pF (560)	В	В	В	В	В	С	С	C	C	C			D
	68pF (680)	В	В	В	В	В	C	C	C	C	C			D
	82pF (820)	В	В	В	В	В	C	С	C	C	С			D
	100pF (101)	В	В	В	В	В	C	С	С	С	С			D

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### **CHIP CAPACITORS**

7-2 1206, 1210, 1812 Sizes (Continued)

	DIELECTRIC								NPO							
	SIZE			1206					1210				1822	1812		
RAT	ED VOLTAGE (VDC)	10	16	25	50	100	10	16	25	50	100	10	16	25	50	100
	120pF (121)	В	В	В	В	В	С	С	С	C	С					D
	150pF (151)	В	В	В	В	В	С	С	С	С	С		*******			D
	180pF (181)	В	В	В	В	В	С	С	С	С	С					D
	220pF (221)	В	В	В	В	В	C	С	С	С	С					D
	270pF (271)	В	В	В	В	В	С	С	С	С	С					D
	330pF (331)	В	В	В	В	В	C	С	С	С	С					D
	390pF (391)	В	В	В	В	В	С	С	С	С	С					D
	470pF (471)	В	В	В	В	В	С	С	С	С	С					D
	560pF (561)	В	В	В	В	В	C	С	С	C	С					D
	680pF (681)	В	В	В	В	В	С	С	С	С	С		1			D
	820pF (821)	В	В	В	В	В	С	С	С	С	С					D
	1,000pF (102)	В	В	В	В	В	С	С	С	C	С	D	D	D	D	D
	1,200pF (122)	В	В	В	В	В	С	С	С	С	С	D	D	D	D	D
0	1,500pF (152)	В	В	В	В	В	С	С	С	С	С	D	D	D	D	D
and	1,800pF (182)	В	В	В	В	В	C	С	С	C	С	D	D	D	D	D
Capacitance	2,200pF (222)	В	В	В	В	В	C	С	С	C	С	D	D	D	D	D
apa	2,700pF (272)	В	В	В	В	В	С	С	С	С	С	D	D	D	D	D
U	3,300pF (332)	В	В	В	В	В	С	С	С	С	С	D	D	D	D	D
	3,900pF (392)	В	В	В	В	В	C	С	С	С	С	D	D	D	D	D
	4,700pF (472)	В	В	В	В	В	С	С	С	С	С	D	D	D	D	D
	5,600pF (562)	В	В	В	В	В	С	С	С	С	С	D	D	D	D	D
	6,800pF (682)	C	C	C	C	С	C	С	С	С	С	D	D	D	D	D
	8,200pF (822)	D	D	D	D	D	С	С	С	С	С	D	D	D	D	D
	0.010µF (103)	D	D	D	D		С	С	С	С	С	D	D	D	D	D
	0.012µF (123)	D	D				С	С	D	D	D	D	D	D	D	D
	0.015µF (153)	D	D				С	С	D	D	D	D	D	D	D	D
	0.018µF (183)	D	D									D	D	D	D	D
	0.022µF (223)	D	D									D	D	D	D	D
	0.027µF (273)	D	D							-		D	D	D	D	D
	0.033µF (333)	D	D									D	D	D	D	D
	0.039µF (393)	G	G													-

<sup>1.</sup> The letter in cell is expressed the symbol of product thickness.

<sup>2.</sup> For more information about products with special capacitance or other data, please contact WTC local representative.



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### **CHIP CAPACITORS**

#### 8. CAPACITANCE RANGE (X7R Dielectric - Based Metal Electrode)

8-1 0402, 0603, 0805 Sizes

	DIELECTRIC				C. Later			X7	'R						
P	SIZE ATED VOLTAGE		04	02				0603		1			0805		ENGINEE AND DESCRIPTION OF THE PERSON OF THE
	(VDC)	10	16	25	50	10	16	25	50	100	10	16	25	50	100
	100pF (101)	N	N	N	N	S	5	S	S	S	В	В	В	В	В
	120pF (121)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	150pF (151)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	180pF (181)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	220pF (221)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	270pF (271)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	330pF (331)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	390pF (391)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	470pF (471)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	560pF (561)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	680pF (681)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	820pF (821)	N	И	N	N	S	S	S	S	S	В	В	В	В	В
	1,000pF (102)	И	И	И	И	S	S	S	S	S	В	В	В	В	В
	1,200pF (122)	N	N	N	N	S	5	S	S	S	В	В	В	В	В
	1,500pF (152)	N	N	N	N	S	S	5	S	S	В	В	В	В	В
	1,800pF (182)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	2,200pF (222)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	2,700pF (272)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	3,300pF (332)	N	N	N	N	S	S	S	5	S	В	В	В	В	В
	3,900pF (392)	N	N	N	N	S	5	S	5	S	В	В	В	В	В
	4,700pF (472)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
	5,600pF (562)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
eu.	6,800pF (682)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
Capacitance	8,200pF (822)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
acit	0.010µF (103)	N	N	N	N	S	S	S	S	S	В	В	В	В	В
ab	0.012μF (123)	N	N	N		S	S	S	S		В	В	В	В	В
_	0.015µF (153)	N	N	N		S	S	S	S		В	В	В	В	В
	0.018µF (183)	N	N	N		S	S	S	S		В	В	В	В	В
	0.022µF (223)	N	N	N		S	S	S	S		В	В	В	В	В
	0.027μF (273)	N	N			S	S	S	S		В	В	В	В	D
	0.033µF (333)	N	N			S	S	S	Χ		В	В	В	В	D
	0.039µF (393)	N	N			S	S	S	X		В	В	В	В	D
	0.047µF (473)	N	N			S	S	S	Χ		В	В	В	В	D
	0.056µF (563)	N				S	S	S	X		В	В	В	В	D
	0.068µF (683)	N	N			S	S	S	Χ		В	В	В	В	D
	0.082µF (823)	N				S	S	S	Χ		В	В	В	В	D
	0.10µF (104)	N	N								В	В	В	В	D
	0.12µF (124)				1						В	В	В	D	
	0.15µF (154)										D	D	D	D	
	0.18µF (184)										D	D	D	D	
	0.22µF (224)										D	D	D	D	
	0.27µF (274)										D	D	D		
	0.33µF (334)										D	D	D		
	0.39µF (394)										D	D	D		
	0.47µF (474)						1		-		D	D	D		-
	0.56µF (564)						,				D	D	D		
	0.68µF (684)							-			D	D	D		
	0.82µF (824)										D	D	D		
	1.0uF (105)					1					D	D	D		

<sup>1</sup> The latter in cell is expressed the symbol of product thickness



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### **CHIP CAPACITORS**

8-2 1206, 1210, 1812 Sizes

	DIELECTRIC			7				X7R								
	SIZE			1206					1210			4		1812		
RATE	D VOLTAGE (VDC)	10	16	25	50	100	10	16	25	50	100	10	16	25	50	10
	100pF (101)															-
	120pF (121)															-
	150pF (151)	В	В	В	В	В										-
	180pF (181)	В	В	В	В	В										-
	220pF (221)	В	В	В	В	В										-
	270pF (271)	В	В	В	В	В										-
	330pF (331)	В	В	В	В	В										1
	390pF (391)	В	В	В	В	В								-		-
	470pF (471)	В	В	В	В	В								-	-	+
	560pF (561)	В	В	В	В	В										ļ
	680pF (681)	В	В	В	В	В										-
	820pF (821)	В	В	В	В	В										1
	1,000pF (102)	В	В	В	В	В	С	С	С	С	С	D	D	D	D	1
	1,200pF (122)	В	В	В	В	В	С	С	С	С	С	D	D	D	D	-
	1,500pF (152)	В	В	В	В	В	С	С	С	C	С	D	D	D	D	1
	1,800pF (182)	В	В	В	В	В	С	С	С	С	С	D	D	D	D	-
	2,200pF (222)	В	В	В	В	В	С	С	С	С	С	D	D	D	D	1
	2,700pF (272)	В	В	В	В	В	С	C	C	C	С	D	D	D	D	1
	3,300pF (332)	В	В	В	В	В	C	C	C	C	С	D	D	D	D	+
	3,900pF (392)	В	В	В	В	В	C	C	С	С	С	D	D	D	D	-
	4,700pF (472)	В	В	В	В	В	C	C	C	C	C	D	D	D	D	_
	5,600pF (562)	В	В	В	В	В	C	C	C	C	C	D	D	D	D	1
eu .	6,800pF (682)	В	В	В	В	В	C	C	C	C	C	D	D	D	D	
Capacitance	8,200pF (822)	В	В	В	В	В	C	C	C	C	C	D	D	D	D	
5	0.010µF (103)	В	В	В	В	В	C	C	C	C	C	D	D	D	D	
ap ap	0.012µF (123)	В	В	В	В	В	C	C	C	C	С	D	D	D	D	
3	0.015µF (153)	В	В	В	В	В	C	C	C	C	C	D	D	D	D	_
	0.018µF (183)	В	В	В	В	В	C	C	C	C	C	D	D	D	D	1
	0.022µF (223)	В	В	В	В	В	C	C	C	C	C	D	D	D	D	-
	0.027µF (273)	В	В	В	В	В	C	C	C	C	C	D	D	D	D	1
	0.033µF (333)	В	В	В	В	В	C	C	C	C	С	D	D	D	D	_
	0.039µF (393)	В	В	В	В	В	C	C	C	C	C	D	D	D	D	
	0.047µF (473)	В	В	В	В	В	C	C	C	C	C	D	D	D	D	_
	0.056µF (563)	В	В	В	В	В	C	С	C	C	C	D	D	D	D	-
	0.068µF (683)	В	В	В	В	В	C	C	C	C	C	D	D	D	D	1
	0.082µF (823)	В	В	В	В	D	C	С	С	C	C	D	D	D	D	1
	0.10µF (104)	В	В	В	В	D	C	C	C	C	C	D	D	D	D	1
FILE	0.12µF (124)	В	В	В	В	D	C	С	C	C	C	D	D	D	D	1
	0.15µF (154)	С	С	С	С	G	C	С	С	C	D	D	D	D	D	1
	0.18µF (184)	С	С	С	C	G	C	С	С	C	D	D	D	D	D	
	0.22µF (224)	С	С	C	С	G	C	С	С	С	D	D	D	D	D	
	0.27µF (274)		С	С	D		C	С	С	C	G	D	D	D	D	
	0.33µF (334)		С	С	D		С	С	С	D	G	D	D	D	D	
	0.39µF (394)	С	С	J	P		С	С	С	D	M	D	D	D	D	
	0.47µF (474)		J	J	P	1	C	С	С	D	M	D	D	D	D	
	0.56µF (564)		J	J	P		D	D	D	D	M	D	D	D	D	
	0.68µF (684)		J	J	P	1	D	D	D	D	k	D	D	D	K	
	0.82µF (824)		J	J	P		D	D	D	D	k	D	D	D	K	T
	1.0uF (105)		1				1	1		1	k					T

- 1. The letter in cell is expressed the symbol of product thickness.
- 2. For more information about products with special capacitance or other data, please contact WTC local representative.
- 3. [^] means the said item is made by NME (Noble Metal Electrode) process.



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### **CHIP CAPACITORS**

### 10. PACKAGING STYLE AND QUANTITY

Size	Thickness (mm)/Sy	mbol -	Paper	tape	Plasti	c tape
	, , , , , , , , , , , , , , , , , , ,	/IIIDUI -	7" reel	13" reel	7" reel	13" reel
0402 (1005)	0.50±0.05	N	10k	50k	-	-
0603 (1608)	0.80±0.07	S	4k	15k		-
(1000)	0.80+0.15/-0.10	Х	4k	15k	-	-
	0.60±0.10	A	4k	15k		
0805 (2012)	0.80±0.10	В	4k	15k	*	
	1.25±0.10	D	-	-	3k	10k
	0.80±0.10	В	4k	15k	-	-
	0.95±0.10	С		-	3k	10k
1206 (3216)	1.15±0.15	J	-	-	3k	10k
1200 (3210)	1.25±0.10	D	-	-	3k	10k
	1.60±0.20	G	-	-	2k	-
	1.60+0.30/-0.10	Р	-	-	2k	
	0.95±0.10	С	-	-	3k	10k
1210 (3225)	1.25±0.10	D	-	-	3k	10k
(3223)	1.60±0.20	G	-		2k	-
	2.50±0.30	М		-	1K	-
1812 (4532)	1.25±0.10	D		-	1k	
(1332)	2.00±0.20	К	-	-	1k	

Unit: pieces

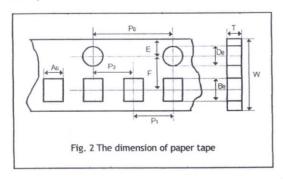


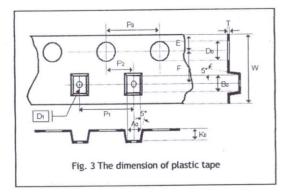
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### **CHIP CAPACITORS**

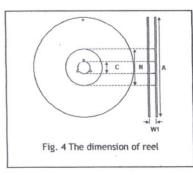
### 11. APPENDIXES

#### ■ Tape & reel dimensions





Size	0402	0603		0805			1206		12	10	1812
Thickness	N	S, X	A	В	C, D, I	В	C, J, D	G	C, D, G	М	D, K
Ao	0.62±0.05	1.02±0.05	1.50±0.10	1.50±0.10	<1.57	2.00±0.10	<1.85	<1.95	<2.97	<2.97	<3.81
Bo	1.12±0.05	1.80±0.05	2.30±0.10	2.30±0.10	<2.40	3.50±0.10	<3.46	<3.67	<3.73	<3.73	<5.30
Т	0.60±0.05	0.95±0.05	0.75±0.05	0.95±0.05	0.23±0.05	0.95±0.05	0.23±0.05	0.23±0.05	0.23±0.05	0.23±0.05	0.25±0.05
K <sub>o</sub>	-	-		-	<2.50	-	<2.50	<2.50	<2.50	<3.00	<2.50
W	8.00±0.10	8.00±0.10	8.00±0.10	8.00±0.10	8.00±0.10	8.00±0.10	8.00±0.10	8.00±0.10	8.00±0.10	8.00±0.10	12.0±0.20
Po	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.100	<b>4.00</b> ±0.10	4.00±0,10
10xP <sub>0</sub>	40.0±0.10	40.0±0.10	40.0±0.10	40.0±0.10	40.0±0.10	40.0±0.10	40.0±0.10	<b>40.0</b> ±0.10	<b>40.0</b> ±0.10	40.0±0.10	40.0±0.10
P <sub>1</sub>	2.00±0.05	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	8.00±0.10
P <sub>2</sub>	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05
Do	1.55±0.05	1.55±0.05	1.55±0.05	1.55±0.05	1.50±0.05	1.50±0.05	1.50±0.05	1.50±0.05	1.50±0.05	1.50±0.05	1.50±0.05
D <sub>1</sub>	-	-	-	-	1.00±0.10	-	1.00±0.10	1.00±0.10	1.00±0.10	1.00±0.10	1.50±0.10
E	1.75±0.05	1.75±0.05	1.75±0.05	1.75±0.05	1.75±0.10	1.75±0.10	1.75±0.10	1.75±0.10	1.75±0.10	1.75±0.10	1.75±0.10
F	3.50±0.05	3.50±0.05	3.50±0.05	3.50±0.05	3.50±0.05	3.50±0.05	3.50±0.05	3.50±0.05	3.50±0.05	3.50±0.05	5.50±0.05



Size	0402,	1812		
Reel size	7"	10"	13"	7"
С	13.0+0.5/-0.2	13.0+0.5/-0.2	13.0+0.5/-0.2	13.0+0.5/-0.2
W <sub>1</sub>	8.4+1.5/-0	8.4+1.5/-0	8.4+1.5/-0	12.4+2.0/-0
A	178.0±0.10	250.0±1.0	330.0±1.0	178.0±0.10
N	60.5+1.0	100.0±1.0	100±1.0	60.5±1.0



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### **CHIP CAPACITORS**

### ■ Recommended soldering conditions

The lead-free termination MLCCs are not only to be used on SMT against lead-free solder paste, but also suitable against lead-containing solder paste. If the optimized solder joint is requested, increasing soldering time, temperature and concentration of  $N_2$  within oven are recommended.

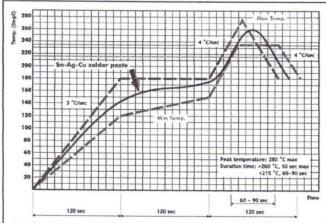


Fig. 6 Recommended IR reflow soldering profile for SMT process with  ${\sf SnAgCu}$  series solder paste.

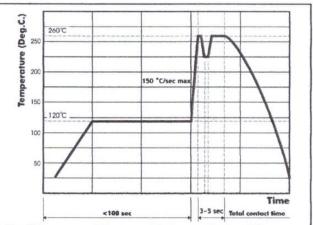


Fig. 7 Recommended wave soldering profile for SMT process with SnAgCu series solder.